## Supporting Information

## Graphene-wrapped yolk-shell of silica-cobalt oxide as highperforming anode for lithium-ion batteries

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## **EXPERIMENTAL SECTION**

Preparation of SiO<sub>2</sub>: SiO<sub>2</sub> was prepared via a Stöber sol-gel process. Aqueous ammonia (13 mL) and isopropanol (63.3 mL) were firstly added to 23.5 mL deionized water to form a uniform mixed suspension. Then added 5 mL of tetraethyl orthosilicate to the mixed suspension and stirred violently for 2 hours. After repeated centrifugation and sufficient drying, SiO<sub>2</sub> (300 nm) was finally obtained. Preparation of GO: GO was synthesized by a modified Hummers' method. First, potassium peroxydisulfate (2.5 g), phosphoric anhydride (2.5 g) and flake graphite (5 g) were added to 50 mL of concentrated sulfuric acid (with a mass fraction of 98%) to form a mixed solution. Then the mixed solution was heated to 80 °C and stirred at a constant temperature for 6 h to complete the pre oxidation process. The pre-oxidized graphite was then washed and dried repeatedly. The pre-oxidized graphite solid and 15 g of potassium permanganate solid were successively added to 115 ml of concentrated sulfuric acid under ice water bath, fully stirred for 3.5 hours, then slowly added 400 ml of ultrapure water, stirred for 2 hours, and then added 20 ml of H<sub>2</sub>O<sub>2</sub> (with a mass fraction of 30%). After repeated centrifugation, washing and dialysis treatment, GO was finally obtained after drying.



Fig. S1 N 1s XPS spectra.

Table S1	The ICP-OES	results of	SiO <sub>2</sub> @CoO/GS.
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Sample	Element	Weight (mg)	Volume (mL)	Dilution factor	Instrument reading (mg L <sup>-1</sup> )	Concentration (wt.%)
SiO <sub>2</sub> @CoO /GS	Si	1.4	50	1	3.91	28.0%
	Co	1.4			7.84	13.954%



Fig. S2 SEM images of (a)  $SiO_2$  and (b)  $SiO_2$ @CoO.



Fig. S3 EDS mapping images of SiO<sub>2</sub>@CoO/GS.



Fig. S4 TEM image of SiO<sub>2</sub>/GS.



Fig. S5 Integrated area of the cyclic voltammetry curves for  $SiO_2$  (a),  $SiO_2/GS$  (b),

SiO<sub>2</sub>@CoO (c) and SiO<sub>2</sub>@CoO/GS (d).



Fig. S6 TEM images of SiO $_2$  (a), SiO $_2/GS$  (b), SiO $_2@CoO$  (c) and SiO $_2@CoO/GS$  (d)

after 40 cycles.

Table S2 Comparison of the cycling and rate performance between this work and

		Initial reversible				
Samples	Methods	capacity		Current	corresponding	Capacity
		$(mA h g^{-1})$ . Performa		densities	capacity	retention
		Coulombic	mbic nce		$(mA h g^{-1})$	(%)
		efficiency (%)				
		764 at 200 mA g <sup>-1</sup> , 47.2	Rate	100	707	100.0
				200	617	87.3
				400	543	76.8
				800	480	67.9
$G \cap O = O / O G$ this work				1600	426	60.3
$S_1O_2(a)C_0O/GS^{\text{units work}}$	solvothermal			3200	374	52.9
				6400	322	45.5
				12800	264	37.3
				100	866	122.5
			Cycling	200	738 after 500 cycles	113
				100	310.4	100.0
				200	270.1	87.0
				500	198.2	55.6
	hydrothermal and thermal treatment	310.2 at 100 mA g <sup>-1</sup> , 57.1	Rate	1000	154.8	49.9
SiO <sub>2</sub> @rGo-Co <sup>1</sup>				2000	112.7	36.3
				5000	70.4	22.7
				100	306.6	98.8
			Cycling	1000	144.9 after 2000	94.03
					cycles	
	Sol-gel and hydrothermal		Rate	50	430	100.0
				100	390	90.7
		120		200	302	70.2
S.O / C3		420 at 100 mA g <sup>-1</sup> , 34		400	209	48.6
SIO <sub>2</sub> /pC <sup>2</sup>				800	127	29.5
				1000	98	22.8
				50	417	97
			Cycling	100	625 after 600 cycles	49.9
	Sol-gel method	1110 at 10 mA g <sup>-1</sup> , 47.5		100	437	100.0
SiO <sub>2</sub> @C <sup>3</sup>			Rate	200	402	92.0
				400	350	80.1
				800	299	68.4
				1000	281	64.3
				2000	222	50.8
				200	410	93.8

those reported in the literature.

			Cycling	100	511 after 100 cycles	73
NCSC <sup>4</sup>	Thermal treatment	565.4 at 100 mA g <sup>-1</sup> , 53.65	Rate	100	530	100.0
				200	475	89.6
				500	410	77.4
				1000	380	71.7
				2000	345	65.1
				5000	273	51.5
				100	600	113.2
			Cycling	2000	254.6 after 500	77.0
					cycles	

## **References:**

1. Q. An, X. Sun, Y. Na, S. Cai and C. Zheng, Chinese Chemical Letters, 2023, 34, 107305.

2. V. Gulavani, S. Kanade, A. Lokhande, M. Ottakam Thotiyl, B. John and A. Yengantiwar, *Energy Tech*, 2024, 2400094.

3. S. Ozen, O. Eroglu and N. Karatepe, Nanotechnology, 2023, 34, 485403.

4. J. Mao, M. Chen, Y. Deng, H. Liu, Z. Ju, Z. Xing and X. Cao, J Mater Sci, 2019, 54, 12767– 12781.